



SEP ELECTRONIC CORP.

KBU601 thru KBU610

6.0 A Single-Phase Silicon Bridge Rectifier Rectifier Reverse Voltage 50 to 1000V



Features

- For purchase please contact ZENIVO,
Assistant E-075583681018-engineer
- Single In-Line terminals array suitable for P.C. board mounting
- Surge overload ratings to 250 amperes peak
- The plastic material used carries Underwriters Laboratory flammability recognition 94V-0
- High temperature soldering guaranteed 265°C/10 seconds/.375"(9.5mm) lead length at 5 lbs (2.3kg) tension

Mechanical Data

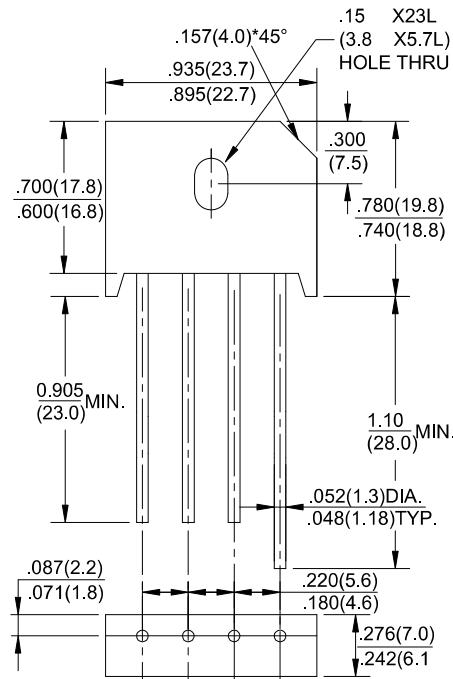
Case: Molded plastic

Terminals: Plated wire leads solderable per
MIL-STD-202, Method 208

Mounting Position: Any

Mounting Torque: 5 in-lb maximum

Weight: 0.3 ounce, 8 grams (approx)



Maximum Ratings & Thermal Characteristics

Rating at 25°C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz.
For Capacitive load derate current by 20%.

Parameter	Symbol	601	602	603	604	606	608	610	unit
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified output current at $T_c=100^\circ\text{C}$ $T_c=45^\circ\text{C}$	IF(AV)				6.0				A
4.0									
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	IFSM				250				A
Rating for fusing ($t < 8.3\text{ms}$)	$I^2 t$				300				$\text{A}^2 \text{sec}$
Typical thermal resistance per element(1)	ReJA				2.5				$^\circ\text{C} / \text{W}$
Operating junction and storage temperature range	TJ, TSTG				-55 to + 150				$^\circ\text{C}$

Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified. Resistive or Inductive load, 60Hz.
For Capacitive load derate by 20 %.

Parameter	Symbol	601	602	603	604	606	608	610	Unit
Maximum instantaneous forward voltage drop per leg at 6.0A	VF				1.1				V
Maximum DC reverse current at rated $TA = 25^\circ\text{C}$ DC blocking voltage per element $TA = 125^\circ\text{C}$	IR				10				μA
					1000				

Notes: (1)Thermal resistance from Junction to Ambert on P.C.board mounting.

Rating and Characteristic Curves ($T_A = 25^\circ\text{C}$ Unless otherwise noted)
KBU601thru KBU610

Fig. 1 Derating Curve for Output Rectified Current

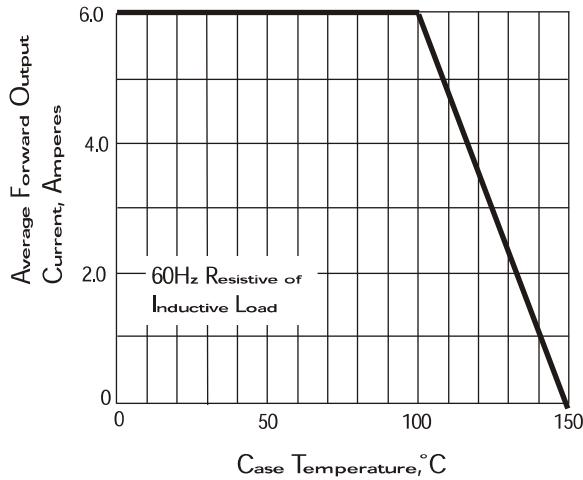


Fig. 3 Typical Instantaneous Forward Characteristics

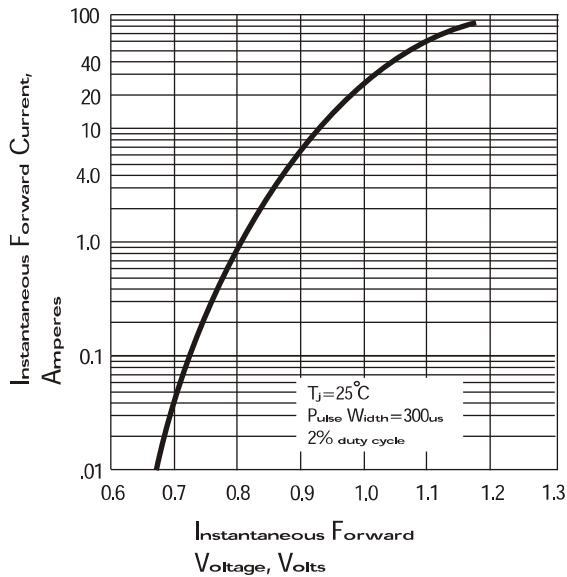


Fig. 2 Maximum Non-repetitive Peak Forward Surge Current

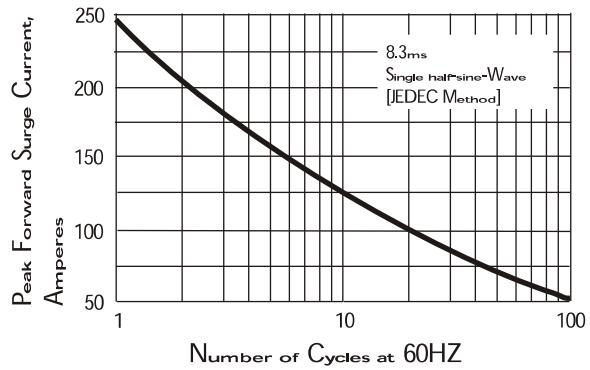


Fig. 4 Typical Reverse Characteristics

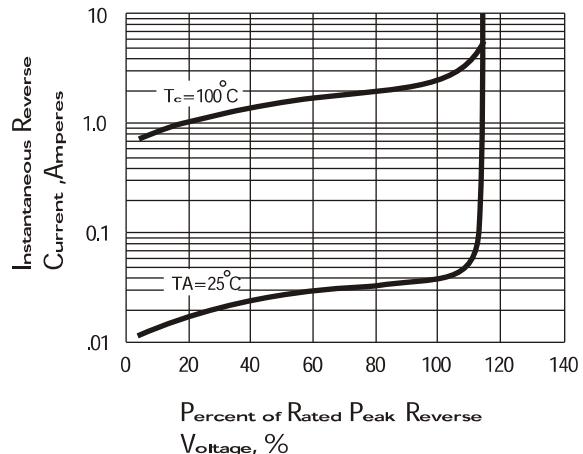


Fig. 5 Typical Junction Capacitance

